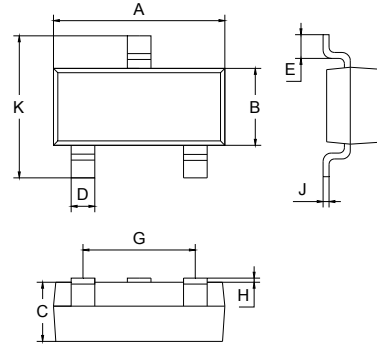


1. BASE
2. EMITTER
3. COLLECTOR

FEATURES

- Epitaxial planar die construction.
- Complementary NPN type available (MMBT3904).
- Collector Current Capability $I_{CM} = -200\text{mA}$.
- Low Voltage(Max:-40V).



SOT-23		
Dim	Min	Max
A	2.70	3.10
B	1.10	1.50
C	1.0 Typical	
D	0.4 Typical	
E	0.35	0.48
G	1.80	2.00
H	0.02	0.1
J	0.1 Typical	
K	2.20	2.60
All Dimensions in mm		

APPLICATIONS

- Ideal for medium power amplification and switching.

ORDERING INFORMATION

Type No.	Marking	Package Code
MMBT3906	2A	SOT-23

MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	Value	UNIT
V_{CBO}	collector-base voltage	open emitter	-40	V
V_{CEO}	collector-emitter voltage	open base	-40	V
V_{EBO}	emitter-base voltage	open collector	-6	V
I_C	collector current (DC)		-100	mA
I_{CM}	peak collector current		-200	mA
I_{BM}	peak base current		-100	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25^\circ\text{C}$	250	mW
T_{stg}	storage temperature		-65 to +150	$^\circ\text{C}$
T_j	junction temperature		150	$^\circ\text{C}$
T_{amb}	operating ambient temperature		-65 to +150	$^\circ\text{C}$

Note Transistor mounted on an FR4 printed-circuit board.



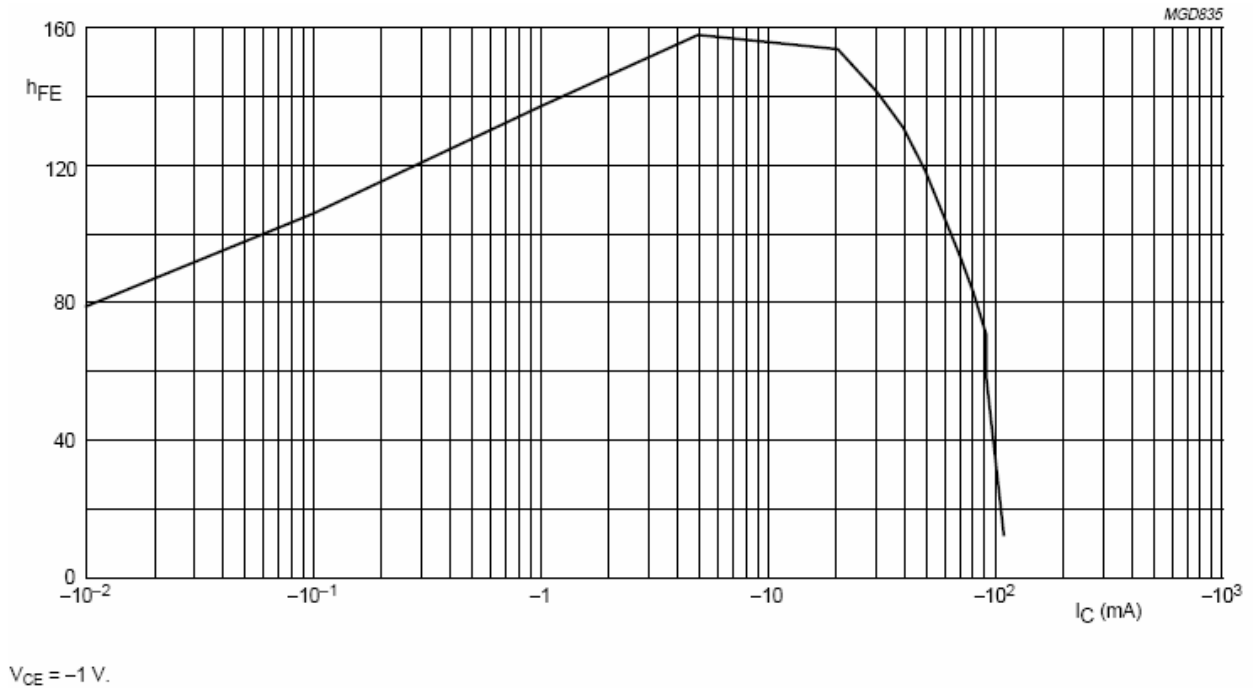
ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = -30 V$	-	-50	nA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = 6 V$	-	-50	nA
h_{FE}	DC current gain	$V_{CE} = -1V;$ $I_C = -0.1mA$ $I_C = -1mA$ $I_C = -10mA$ $I_C = -50mA$ $I_C = -100mA$	60 80 100 60 30	- - 300 - -	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10mA; I_B = 1mA$	-	-200	mV
		$I_C = -50mA; I_B = -5mA$	-	-300	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = -10mA; I_B = -1mA$	-	-850	mV
		$I_C = -50mA; I_B = -5mA$	-	-950	mV
C_c	collector capacitance	$I_E = I_e = 0; V_{CB} = -5 V;$ $f = 1 MHz$	-	4.5	pF
C_e	emitter capacitance	$I_C = I_e = 0; V_{EB} = -500 mV;$ $f = 1 MHz$	-	10	pF
f_T	transition frequency	$I_C = -10mA; V_{CE} = -20 V;$ $f = 100MHz$	250	-	MHz
NF	noise figure	$I_C = -100\mu A; V_{CE} = -5V;$ $R_S = 1 k\Omega; f = 10Hz to 15.7 kHz$	-	4	dB
Switching times (between 10% and 90% levels);					
t_{on}	Turn-on time	$I_{Con} = -10mA; I_{Bon} = -1mA;$ $I_{Boff} = -1mA$	-	65	ns
t_d	delay time		-	35	ns
t_r	rise time		-	35	ns
t_{off}	turn-off time		-	300	ns
t_s	storage time		-	225	ns
t_f	fall time		-	75	ns

Note Pulse test: $t_p \leq 300 ms; d \leq 0.02.$



TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified



DC current gain; typical values.

Package	Reel	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
SOT-23	3000pcs	7inch	45,000pcs	203×203×195	180,000pcs	438×438×220